NSN 5961-01-070-2815

Demilitarization:

No Fiig: A110a0

Semiconductor Device Set - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-070-2815 **Inclosure Material:** Ceramic all semiconductor device diode **Overall Length:** 0.215 inches all semiconductor device diode Overall Diameter: 0.120 inches all semiconductor device diode **Function For Which Designed:** Varactor diode **Component Function Relationship:** Matched **Component Name And Quantity:** 6 semiconductor device diode **Mounting Method:** Terminal all semiconductor device diode **Field Force Effect Type:** Electrostatic charge **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 42.0 reverse breakdown voltage, dc all semiconductor device diode **Power Rating Per Characteristic:** 2.0 watts small-signal input power, common-collector absolute all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction all semiconductor device diode **Test Data Document:** 13499-922-6104 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 connector, coaxial all semiconductor device diode Shelf Life: N/a **Unit Of Measure:**